NSN 5961-01-098-9353



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-098-9353 **Inclosure Material:** Metal **Overall Length:** Between 0.694 inches and 0.766 inches Overall Diameter: Between 0.365 inches and 0.385 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Thread Size:** 0.164 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 35.0 collector to emitter voltage/static/base open and 65.0 collector to base voltage, dc and 4.0 emitter to base voltage, dc and 35.0 breakdown voltage, collector-to-emitter, base open and 65.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter and 4.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 1.00 amperes source cutoff current and 1.00 amperes zero-gate-voltage source current preset **Power Rating Per Characteristic:** 15.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unc **Terminal Type And Quantity:** 4 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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